


	<h2 style="color: red;">IRFB9N65APBF</h2>
	<b>Hersteller-Teilenummer:</b> IRFB9N65APBF
	<b>Hersteller / Marke:</b> Vishay / Siliconix
	<b>Teil der Beschreibung:</b> MOSFET N-CH 650V 8.5A TO-220AB
	<b>Datenblätter:</b> <ul style="list-style-type: none"> <li> <a href="#">1.IRFB9N65APBF.pdf</a></li> <li> <a href="#">2.IRFB9N65APBF.pdf</a></li> </ul>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 37370 pcs Stock Available.
	<b>Liefern von:</b> Hong Kong
	<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	IRFB9N65APBF
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 650V 8.5A TO-220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	37370 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	167W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.5A (Tc)
Rds On (Max) @ Id, Vgs	930 mOhm @ 5.1A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	48nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1417pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube

IRFB9N65APBF ist neu im Original, Suche IRFB9N65APBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFB9N65APBF Vishay / Siliconix mit Garantie und Vertrauen. Anfrage IRFB9N65APBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>IRFBA1405P</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 174A SUPER-220</p>	 <p><b>IRFBA1404PPBF</b> International Rectifier (Infineon Technologies) MOSFET N-CH 40V 206A SUPER-220</p>	 <p><b>IRFB9N65A</b> Vishay / Siliconix MOSFET N-CH 650V 8.5A TO-220AB</p>	 <p><b>IRFB9N60APBF</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 9.2A TO-220AB</p>
 <p><b>IRFBA1404P</b> International Rectifier (Infineon Technologies) MOSFET N-CH 40V 206A SUPER-220</p>	 <p><b>IRFBA1405PPBF</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 174A SUPER-220</p>	 <p><b>IRFB9N65APBF</b> Electro-Films (EFI) / Vishay MOSFET N-CH 650V 8.5A TO-220AB</p>	 <p><b>IRFB9N65</b> IR/VISHAY IRFB9N65 IR/VISHAY</p>

### heiße Teile

Mehr

 IRFB7446GPBF	 IRFB7446PBF	 IRFB7537	 IRFB7540	 IRFB7545
 IRFB7545PBF	 IRFB7546	 IRFB7546PBF	 IRFB7740	 IRFB7740PBF
 IRFB7N60C3PBF	 IRFB812PBF	 IRFB812TRPBF	 IRFB9N30A	 IRFB9N30A
 IRFB9N30APBF	 IRFB9N30APBF	 IRFB9N60A	 IRFB9N60A	 IRFB9N60APBF
 IRFB9N60APBF	 IRFB9N65	 IRFB9N65A	 IRFB9N65A	 IRFB9N65APBF
 IRFBA1404P	 IRFBA1404PPBF	 IRFBA1405P	 IRFBA22N50A	 IRFBC20-030
 IRFBC20LPBF	 IRFBC20LPBF	 IRFBC20PBF	 IRFBC20PBF	 IRFBC20SPBF
 IRFBC20SPBF	 IRFBC20STRL	 IRFBC20STRL	 IRFBC20STRLPBF	 IRFBC20STRLPBF
 IRFBC20STRR	 IRFBC20STRR	 IRFBC30ALPBF	 IRFBC30ALPBF	 IRFBC30AS
 IRFBC30AS	 IRFBC30ASPBF	 IRFBC30ASPBF	 IRFBC30ASTRL	 IRFBC30ASTRL

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